

Cascades in transport and optical conductivity of Twisted Bilayer Graphene

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Using a combined Dynamical Mean Field Theory and Hartree (DMFT+H) calculation we study the transport and optical properties of the 8-band heavy fermion model for Twisted Bilayer Graphene (TBG) in the normal state. We find resistive states around integer fillings which resemble the ones observed in transport experiments. From a Drude fitting of the low frequency optical conductivity, we extract a very strongly doping-dependent Drude weight and scattering rate, resetting at the integers. For most dopings, particularly above the integers, the Drude scattering rate is high but notably smaller than that of the local electrons. This highlights the important role of itinerant electrons in the transport properties, despite their limited spectral weight on the flat bands. At far infrared frequencies, the optical conductivity exhibits cascades characterized by highly asymmetric resets of the intensity and oscillations in the interband peak frequencies.

Among the plethora of correlated states in magic angle TBG, the cascades in the Density of States (DOS) [1–4] and in the inverse compressibility [5–7], and the resistive states [6, 8–12], are the signatures of the electronic correlations that remain up to the highest temperatures. Experimentally, maxima in the resistivity as a function of doping appear around integer fillings up to temperatures much higher than those at which insulating behavior (resistivity increasing as the temperature decreases) is observed and, in many cases, even when the latter is absent [6, 8–12]. Evidence of symmetry breaking order has been reported only up to a few kelvin. In many strongly correlated materials, Mott-like physics produces a redistribution of the spectral weight, even if the correlated material is in its normal state, above any symmetry-breaking ordering, or it is a metal [13–22]. However, due to the intrinsic topology of the TBG flat bands, most explanations of the correlated states observed in these systems, including those resilient with temperature, involved the assumption of symmetry breaking [1–3, 5, 23–27].

The dichotomy between the local and topological properties can be incorporated within heavy fermion-like descriptions which include the remote bands [18, 19, 28–30]. In the different heavy fermion models for TBG, strongly correlated p_+ and p_- orbitals centered in the AA region of the moiré unit cell, AA_p orbitals in the following, account for the most part of the spectral weight of the flat bands and are coupled to more itinerant orbitals only around Γ . Once the effect of the interactions are properly incorporated, the AA_p orbitals tend to form local moments or heavy quasiparticles, depending on their filling [19–22]. The electronic spectral weight $A(\mathbf{k}, \omega)$ obtained from DMFT calculations shows a characteristic momentum-selective incoherence and clear signatures of the Hubbard bands [19, 20] that could be studied in the

future with nanoARPES or the Quantum Twisting Microscope [31–33]. Due to the intrinsic topology of the flat bands of TBG, the spectrum differs from that of standard Hubbard models and Mott insulators [19]. Without the need to involve any symmetry-breaking ordering, in the normal state, the spectral weight redistribution induced by the correlations produces a cascade spectrum in the DOS and asymmetric peaks in the inverse compressibility [19–22] consistent with those observed experimentally [1–7]. Little is known about the transport properties of TBG within this heavy fermion framework and the type of electrons governing them [11, 34].

Optical spectroscopy has played a pivotal role in identifying the signatures of electronic correlations in many materials [14]. Optical transitions conserve spin, valley and momentum, making optical probes an ideal set-up to explore the spectrum of moiré heterostructures [35?–42]. At low frequencies, it provides information on the scattering rate of the carriers and their contribution to transport. Due to experimental challenges, doping dependent optical measurements of TBG are not available yet but they could be soon achieved [39, 41? , 42].

In this work, we apply the same heavy fermion-like description that we used earlier to reproduce the cascades in the DOS and the inverse compressibility [19] to study the doping dependence of the dc and optical conductivities. The resulting optical spectrum shows a characteristic pattern with asymmetric resets in intensity as a function of doping and oscillations in the onset frequencies of the interband transitions. The resets at integer fillings also appear in the dc conductivity and can explain the resistive states observed in transport experiments. A Drude analysis of the low frequency conductivity suggests a prominent role of the scarce itinerant electrons in the transport properties.

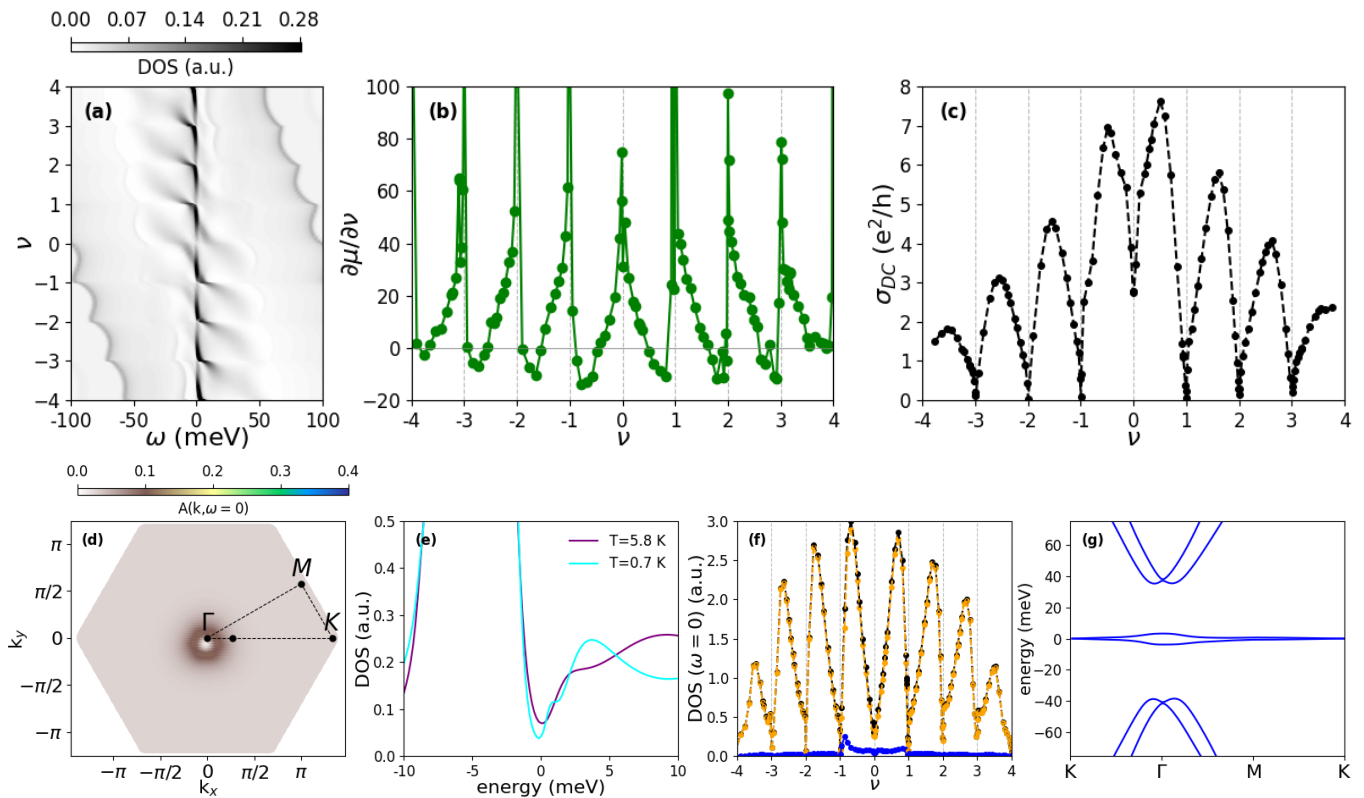


FIG. 1. (a) Doping and energy dependent DOS, (b) inverse compressibility and (c) dc conductivity of TBG versus doping ν . (d) Spectral weight at the Fermi level at CNP within the first Brillouin zone showing small pockets close to Γ . (e) Zoom of the low energy DOS for $\nu = 1$ at temperatures $T=5.8$ K and $T=0.7$ K. (f) DOS at the Fermi level versus doping, including the total DOS (black), the AA_p DOS (orange) and the itinerant orbitals DOS (blue). The quantities displayed in (a)-(f) have been obtained within the DMFT+H calculations. (g) Non-interacting band structure corresponding to the 1.08° TBG studied.

We focus on a slightly particle-hole asymmetric TBG with twist angle $\theta = 1.08^\circ$ and interlayer tunneling ratio between the AA and AB regions of the moiré unit cell $w_0/w_1 = 0.7$, Fig. 1(g) [43–45]. We fit the band structure with an 8 orbital model per valley and spin [19, 28, 43, 46] with topologically fragile flat bands. To calculate the interactions between the orbitals in the effective model, we assume a $1/r$ interaction between the electrons at the carbon atoms and relative dielectric constant $\epsilon = 16$ [43]. We distinguish two types of orbitals: local AA_p and itinerant lc . The two AA_p orbitals, with p_+ and p_- symmetries, centered at the AA region of the unit cell account for the spectral weight of the flat bands everywhere except close to the Γ point. The intra-unit cell interaction between these local AA_p orbitals, $U \sim 32.6$ meV, is much larger than their bandwidth. These orbitals are strongly correlated [19, 28] and tend to form local moments. The lc orbitals are less correlated. The model resembles an extended heavy-fermion like model with a strongly \mathbf{k} -dependent hybridization between the local AA_p and the itinerant lc orbitals, concentrated around Γ , see Fig. S1 [43] and [18, 19, 21, 28, 29, 47–49]. The interactions involving the itinerant orbitals are of order $U/2$ and cannot be neglected [1, 19, 28, 29, 43]. As in our previous work, we treat the intra and inter-orbital

onsite interaction U between the AA_p orbitals within DMFT and the other interactions at a mean field Hartree level, within a double self-consistency loop (DMFT+H), see [19, 43]. Temperature is 5.8 K except otherwise indicated. Spontaneous symmetry-breaking is not allowed in the calculation.

Consistent with our previous work [19] and with experimental results [1, 5], the DOS and the inverse compressibility in Fig. 1(a)-(b), respectively, show cascades of spectral weight and asymmetric saw-tooth peaks resetting at integer values of doping. Regions of negative inverse compressibility appear below the integer values after the contribution of the gate is taken into account [20, 43], in agreement with experimental data. The ratio between the AA_p onsite interaction U , and Δ , the energy gap between the remote and the flat bands at Γ , $U/\Delta = 0.85$, is smaller than the one used in our previous calculations ($U/\Delta = 2$ in [19]) and in other works [34]. This prevents the remote bands from crossing the chemical potential at dopings $|\nu| < 4$ due to the strong Hartree deformation of the bands at Γ , see Fig. 3(d)-(e) and [43]. Consequently, the system is insulating at $|\nu| = 4$, instead of metallic as in [19, 34].

A strong resetting behavior with minima in the dc conductivity is also seen in Fig. 1(c). These minima around

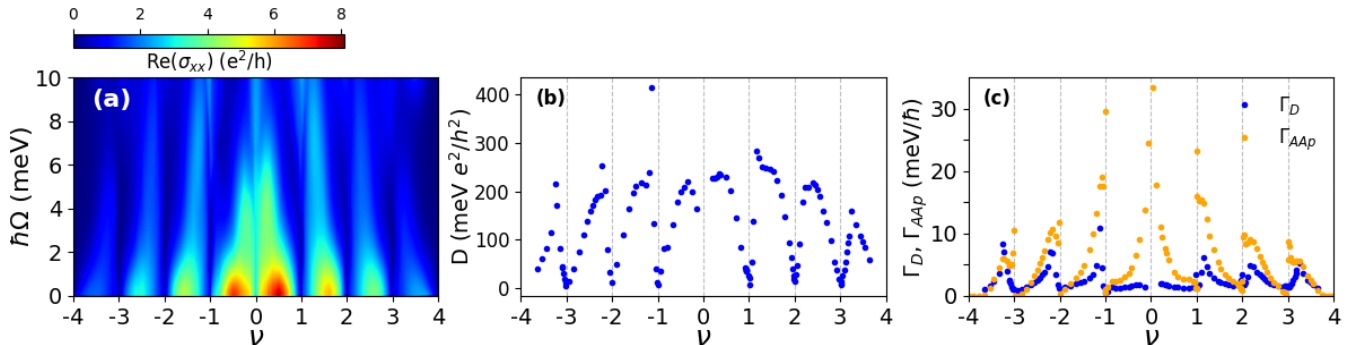


FIG. 2. (a) Low frequency DMFT+H optical conductivity versus doping and energy. (b) Drude weight and (c) scattering rate obtained from the fitting of the optical conductivity to a Drude model. In (c) the Drude scattering rate is compared to the one obtained from the real frequency DMFT self-energy of the local AA_p electrons $\hbar\Gamma_{AAp} = -2\Sigma(\omega = 0)$.

integers produce resistive peaks as those found in transport measurements up to tens of kelvin [6, 8–12]. Our calculations hence show that the presence of these peaks in the resistivity does not require symmetry-breaking, forbidden in the computation. At the Charge Neutrality Point (CNP), the conductivity is notably enhanced with respect to the one at the other integers and to the one expected for a Dirac semimetal. This is a consequence of the presence of compensated electron and hole pockets close to Γ , Fig. 1(d). These pockets emerge due to the hybridization between the itinerant electrons at Γ and the local AA_p, whose spectral weight is shifted to the Hubbard bands at higher energies, Fig. 3(d). The suppression of the DOS at non-zero integers was previously interpreted by us [19] and others [3, 20] as a pseudogap. A recent work has studied the formation of decoupled moments in isolated topological bands and related it to the TBG flat bands [50] and finds hard gaps at non-zero integers. In Fig. 1(f) we compare the DOS close to the Fermi level at $\nu = 1$ at $T=5.8$ K, the temperature of the calculations, and at $T=0.7$ K, a temperature at which the incoherent spectral weight is strongly suppressed. The numerical data at these temperatures seem more consistent with an asymmetric nodal gap or a pseudogap than with a hard gap, but we cannot rule out the latter appearing at larger interactions.

To get insight into the nature of the carriers, we fit the real part of low-frequency optical conductivity $Re\sigma_{xx}(\Omega)$, Fig. 2(a), to a Drude model. See SI [43] for details on the fitting. The doping dependence of the dc conductivity results from the interplay between the variation with doping of the Drude weight D and that of the Drude scattering rate Γ_D , as $\sigma_{DC} = D/(\pi\Gamma_D)$. Both quantities show asymmetric resets with maxima above the integers, as shown respectively in Fig. 2(b) and (c). Γ_D is sizeable, of several $meV\hbar^{-1}$ and larger than the temperature. Nevertheless, it is considerably smaller than Γ_{AAp} , the scattering rate of the AA_p local electrons, except at very high doping and right below the integers, see Fig. 2(c). This difference suggests a large contribution of the itinerant lc electrons to the transport properties [11, 34], despite

their limited presence at the Fermi level, see Fig. 1(f). The contribution of the AA_p electrons to the dc conductivity, already small in the non-interacting and Hartree approximations due to their small velocity [43], is further suppressed in the DMFT calculations by their large scattering rate Γ_{AAp} . A prominent role of the itinerant electrons in the conductivity is also consistent with the opposite asymmetry of the Drude weight and the DOS at the Fermi level with respect to the integer fillings, Fig. 2(b) and Fig. 1(f).

The far infrared optical spectrum obtained from the DMFT+H calculations, Fig. 3(a), displays an unconventional and strong doping dependence. At these frequencies, the optical conductivity is controlled by interband transitions between the flat and the remote bands, with strongly \mathbf{k} -dependent velocity matrix elements [43], largest around Γ due to the hybridization between the different types of orbitals. The most striking feature in Fig. 3(a) is the strong asymmetric resets in the intensity around the integers, accompanied by oscillations in the energies at which the maximum intensity appears. At each doping, the spectrum profile shows two prominent peaks. The peak energies decrease with increasing electron or hole doping, with resets and oscillations occurring within this two-peak spectrum. The DMFT+H optical conductivity is very different to the one found in the absence of interactions in Fig. 3(b). Without interactions, the energy of the interband transitions does not depend on the filling, the doping dependence of the optical conductivity is uniquely controlled by Pauli's exclusion principle and the transitions around Γ are forbidden only for almost full or empty flat bands.

The optical conductivity obtained with the interactions treated at the Hartree level, Fig. 3(c), captures the two peak structure and the decreasing onset of the transitions with doping. In the Hartree approximation, adding or removing electrons bends the flat bands close to Γ and shifts the energy of the remote bands with respect to the chemical potential [28, 51–54], Fig. S2(a-b) in [43]. These effects, inherited in the DMFT+H spectrum, Fig. 3(a), modify the energy of the interband transitions and the

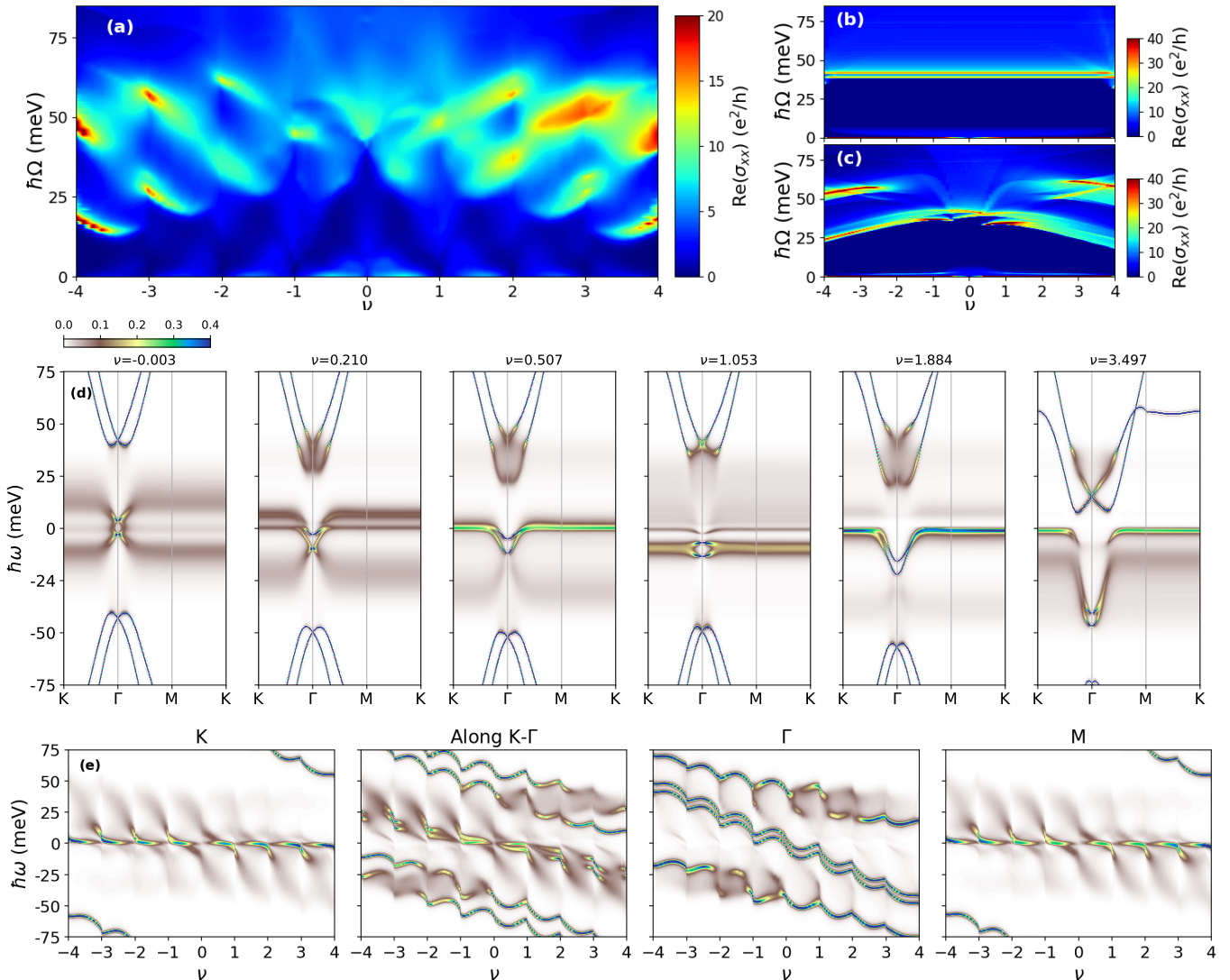


FIG. 3. (a) DMFT+H optical conductivity showing resets in the intensity at integer fillings, oscillations in the frequency at which the intensity peaks. (b)-(c) Optical spectrum respectively in the absence of interactions and in the Hartree approximation. (d) Spectral weight $A(\mathbf{k}, w)$ from the DMFT+H calculations at doping $\nu = 0, 0.21, 0.5, 1.05, 1.88$ and 3.5 as a function of momentum; and (e) Spectral weight $A(\mathbf{k}, w)$ as a function of doping ν at fixed momenta: From left to right K , along $K - \Gamma$ direction, Γ , and M , marked in Fig. 1(d). The colorbar in (d) is also valid for (e).

frequency at which the optical intensity peaks. The bending of the flat bands can also alter the occupation of the states and change an interband transition from forbidden to allowed, or viceversa, particularly in the region close to Γ that contributes the most to the spectrum [43].

The Hartree approximation cannot account for the strong resets in the optical intensity and the oscillations of the frequency of the transitions found in the DMFT+H calculations. The oscillations of the peak frequencies originate in the oscillations of the band energies, early seen experimentally in the cascade STM spectrum at remote band energies [55] and reproduced in the DMFT+H DOS in Fig. 1(a) and [19, 20]. These oscillations can be seen in the \mathbf{k} and doping dependent bandstructure in Fig. 3(d) and [43], but they are better resolved when the spectral weight $A(\mathbf{k}, w)$ is plotted at fixed \mathbf{k} as a function of energy and doping, Fig. 3(e). $A(\mathbf{k}, w)$ clearly shows os-

cillations, not only at the remote band energies but also at the flat bands, specially around the Γ point [19]. The spectral weight $A(\mathbf{k}, w)$ also displays a strongly \mathbf{k} and doping dependent alternation of incoherent and coherent flat bands at the Fermi level. This alternation results from the formation of local moments, which progressively evolve into more coherent heavy quasiparticles, just below the integer dopings [19, 20, 22]. This doping dependent incoherence produces the resets in the intensity of the optical conductivity at integer fillings in Fig. 3(a). Another difference with the Hartree spectrum is the gap in the latter between the flat-remote interband transitions and those within the flat bands at THz frequencies, Fig. 3(c) and Figs. S2 and S3 in [43]. In contrast, at these intermediate frequencies the DMFT+H optical conductivity shows finite intensity due to transitions between the flat bands and the incoherent Hubbard bands.

In summary, we have shown that the spectral weight reorganization due to the formation of local moments and heavy quasiparticles in TBG produces resistive peaks as a function of doping and a very unconventional optical conductivity spectrum, with asymmetric resets of the intensity at integer fillings and oscillations in the intensity peak frequencies. The same mechanism was previously shown to reproduce the cascades in the STM and compressibility measurements in TBG. This spectral weight reorganization does not require symmetry breaking: It happens already in the normal state. Therefore, it can explain the experimental observation of resistive states up to temperatures much higher than those at which the symmetry-breaking order has been observed. Our analysis of the low frequency conductivity has also allowed us to shed light on the important role of the itinerant electrons on the transport properties, despite being scarce at the Fermi level. We expect the doping dependence of the optical conductivity discussed here to be robust to the details of the underlying TBG band structure, but the exact energies at which the transitions appear will depend on the experimental TBG parameters, such as the tunneling ratio w_0/w_1 .

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SUPPLEMENTARY INFORMATION

Model and Methods

Fig. S1(a) shows the non-interacting band structure for one of the valleys, obtained from the continuum model (black) for a 1.08° TBG with $v_F = 0.87 \times 10^6$ m/s, interlayer tunneling ratio between the AA and AB regions $w_0/w_1 = 0.7$ and AB tunneling amplitude $w_1 = 110$ meV, and the effective 8-orbital fitting used (blue) [44–46]. In the continuum model we have kept the $\sin(\theta/2)$ term. This results in slightly particle hole asymmetric bands. The flat bands width at the Γ point is 7.7 meV and 1.4 meV at M. The onset of the remote conduction and valence bands is respectively at 35.5 and 37 meV.

The effective moiré model includes 8 orbitals per valley and spin: p_+ and p_- orbitals centered at the triangular lattice formed by the AA regions (AA_p), one s orbital at AA (AA_s), two p_z orbitals at the AB and BA honeycomb lattice, ($AB/BA-p_z$) and three s orbitals at the kagome

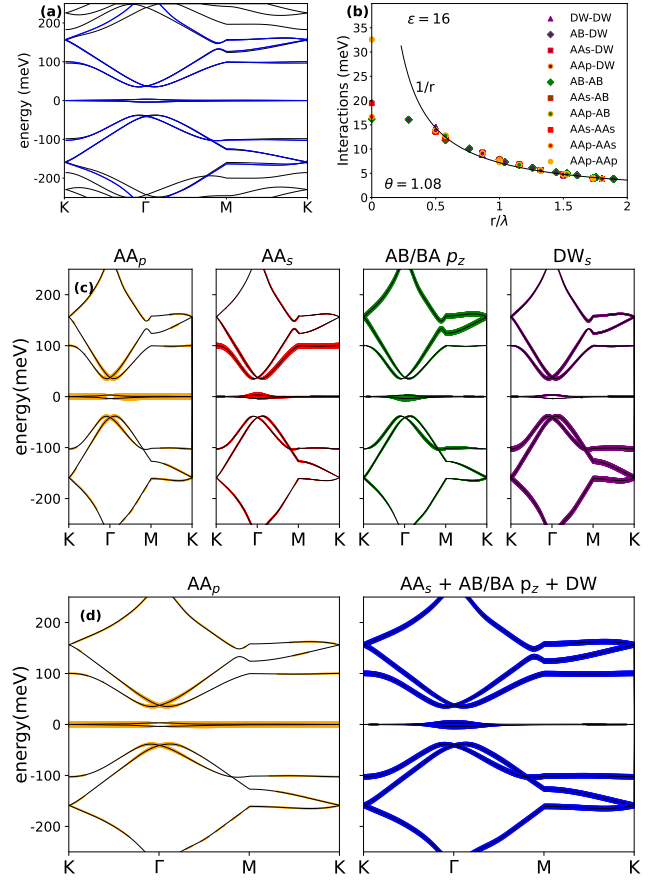


FIG. S1. (a) Non-interacting band structure obtained from the continuum model (black) and the 8 orbital fitting (blue). (b) Density-density interactions between the orbitals of the effective 8-orbital model used in the calculation as a function of the distance between their centers. (c) Orbital decomposition of the non-interacting bands, distinguishing the four types of orbitals in the model. (d) Decomposition of the non-interacting bands into strongly correlated AA_p orbitals and less correlated lc orbitals.

lattice formed by the domain wall regions separating the AB/BA points (DW_s). The moiré tight-binding obtained from the fitting can be found in [56]. The orbital decomposition of the bands is shown in Fig. S1(c). The spectral weight of the AA_s , $AB/BA-p_z$ and DW_s is spread over a large range of energies, much larger than the effective interactions in the model, see Fig. S1(b). Therefore, these orbitals are not expected to be strongly correlated in a Mott sense and are called less correlated lc or itinerant throughout the main text. On the other hand, the spectral weight of the AA_p orbitals is strongly concentrated on the flat bands, which are much narrower than their onsite interaction U . As a consequence, the AA_p orbitals will be sensitive to Mott correlations and form local moments, see [18, 28, 29].

The interactions between the moiré orbitals are calculated projecting the moiré Wannier functions onto the

two layers atomic sublattices and assuming a $1/r$ decay of the interaction between the electrons in the carbon atoms and a relative dielectric constant $\epsilon = 16$. We do not find significant differences between the density-density interactions in the different valleys. The intra and inter-orbital density-density interactions used in the self-consistent calculation are shown in Fig. S1(b). The onsite AA_s - AA_p interaction has been reduced a 26 % from the computed value to decrease the small particle-hole asymmetry induced by the 8- orbital fitting when the interactions are included. The inter-site density-density interactions are kept up to a distance of 7 neighboring moiré unit cells in the self-consistent calculation and to compute the effect of the gate in the chemical potential. Exchange, Hund and pair hopping terms are much smaller than the density-density terms and we neglect them here [28].

To avoid double-counting the effect of the interactions we subtract the Hartree contribution at the CNP [52] produced by all the interactions, including U . For finite doping the energy cost to charge the unit cell is compensated by the gate, whose contribution V_g is subtracted from the chemical potential to calculate the inverse compressibility. We approximate V_g as the average energy required to add ν electrons homogeneously to the 8 orbitals included in the model.

$$V_g = e^2 \frac{\nu}{32^2} \sum_{a,\sigma,\xi} \sum_{b,\sigma',\xi',m_j} U_{ab,\sigma,\sigma',\xi,\xi'}^{m_j} \quad (\text{S1})$$

with $U_{ab,\sigma,\sigma',\xi,\xi'}^{m_j}$ labelling all the density-density interactions included in the DMFT+H calculation. Here a, b are orbital indices running from 1 to 8, ξ, ξ' are valley indices, σ, σ' spin indices and m_j labels the neighboring cells in which the density-density interactions are finite. In the summation above we exclude the contribution from orbitals $b = a$ centered at the same unit cell with the same spin and valley.

V_g can be understood as a capacitive coupling to the gate $V_g = e^2 C_g^{-1} \nu$ and is subtracted from the global chemical potential [19]. The values of V_g and the global chemical potential are sensitive to the maximum distance up to which the interactions are included, but their difference is quite insensitive for the seven moiré unit cells kept here. For the dielectric constant used in the calculation $\epsilon = 16$, $e^2 C_g^{-1} = 187.4$ meV. The prescription to account for the gate contribution here is different to the one in [19], where the effect of the gate was accounted by a redefinition of the chemical potential to the value used in the DMFT loop and not fully subtracted. It is also different to the one used in [20].

The impact of the interactions on the spectral weight is calculated with a double self-consistent DMFT+Hartree loop, as detailed in [19], using the CTQMC impurity solver developed in [57, 58]. The analytic continuation is performed with a maximum entropy method [59] as

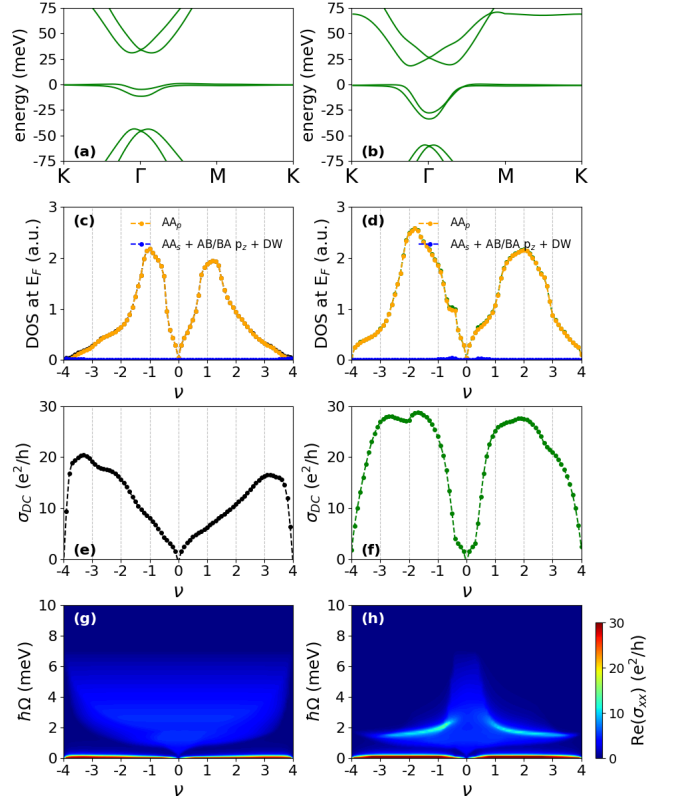


FIG. S2. (a) and (b) Band structure for the 1.08° and $w_0/w_1 = 0.7$ twist angle TBG in the Hartree approximation corresponding to $\nu=1.0$ and $\nu=3.5$ calculated using the same interactions as in the DMFT+H calculations. (c), (e) and (g) Orbital resolved density of states for AA_p and lc orbitals, dc conductivity and low frequency optical conductivity, respectively, as a function of doping ν in the absence of interactions. (d), (f) and (h) Same in the Hartree approximation.

implemented in [58]. The value of Γ_{AA_p} in Fig. 2 is computed at $\omega = 0$ after doing the analytic continuation.

We focus on the real part of the longitudinal optical conductivity $Re(\sigma_{\alpha\alpha})$, calculated using Kubo formula. For brevity, in the text we refer to it simply as the conductivity. For the DMFT+H conductivity we use

$$Re(\sigma_{\alpha\alpha}(\Omega)) = 4 \frac{2}{\sqrt{3}} \frac{\pi e^2}{\hbar} \int d\omega \sum_{\mathbf{k}} \text{Tr} \left[\mathbb{A}(\omega + \Omega, \mathbf{k}) \mathbb{V}_\alpha(\mathbf{k}) \times \mathbb{A}(\omega, \mathbf{k}) \mathbb{V}_\alpha(\mathbf{k}) \right] \frac{f(\omega) - f(\omega + \Omega)}{\Omega}. \quad (\text{S2})$$

Here the factor 4 accounts for the valley and spin degeneracy, $2/\sqrt{3}$ accounts for the geometrical factor of the triangular lattice, $f(\omega)$ is the Fermi distribution function and $\mathbb{A}(\omega, \mathbf{k})$ and $\mathbb{V}_\alpha(\mathbf{k})$ are matrices. $\mathbb{A}(\omega, \mathbf{k})$ is the spectral function and $\mathbb{V}_\alpha(\mathbf{k})$ are the velocity vertices in the α direction:

$$\mathbb{V}_\alpha(\mathbf{k}) = \frac{1}{\hbar} \frac{\partial \mathbb{H}}{\partial k_\alpha} \quad (\text{S3})$$

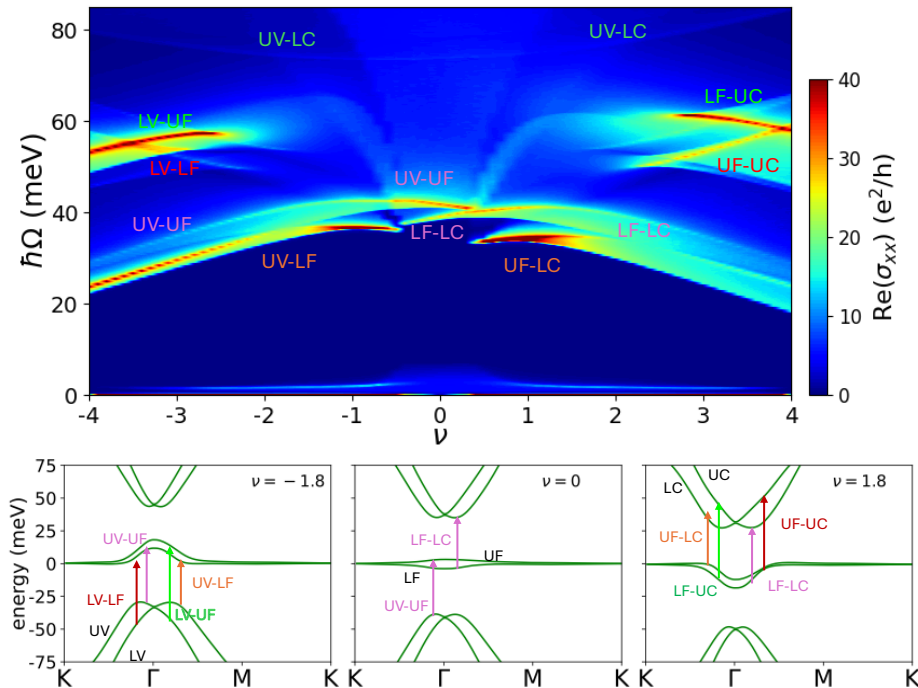


FIG. S3. Identification of the most important interband transitions between the flat and the remote bands which contribute to the optical conductivity in the different doping ranges with interactions treated at the Hartree level.

with \mathbb{H} the tight binding Hamiltonian. For the specific symmetry of the lattice considered here $Re(\sigma_{xx}) = Re(\sigma_{yy})$, with X and Y the cartesian axis. All the calculations refer to σ_{xx} .

To calculate the dc conductivity we take the limit $\Omega = 0$ analytically in Eq. (S2) before computing σ_{dc} numerically.

$$\sigma_{DC} = 4 \frac{2}{\sqrt{3}} \frac{\pi e^2}{\hbar} \int d\omega \sum_{\mathbf{k}} \text{Tr} [\mathbb{A}(\omega, \mathbf{k}) \mathbb{V}_{\alpha}(\mathbf{k}) \mathbb{A}(\omega, \mathbf{k}) \mathbb{V}_{\alpha}(\mathbf{k})] \times \left(-\frac{\partial f(\omega)}{\partial \omega} \right) \quad (\text{S4})$$

To avoid unwanted inaccuracies for vanishing scattering rate [60] we restrict the calculation of σ_{dc} and the Drude fittings below to $\nu < |3.7|$. The calculations in the Hartree and the non-interacting cases are performed using the expression derived in [61].

Non-interacting and Hartree approximations

Analyzing the doping dependence of the conductivity and the DOS in the non-interacting and Hartree approximation helps understanding the spectrum in the DMFT+H approximation. The band structure calculated in the Hartree approximation for dopings $\nu = 1.0$ and $\nu = 3.5$ is shown in Figs. S2(a)-(b). It shows

the characteristic Hartree bending with increasing doping [28, 51, 52, 54] with respect to the non-interacting band structure in Fig. 1(g). The bending is opposite for electron and hole doping. This bended shape is inherited in the DMFT+H band structure in Figs. S4 and S5.

The DOS at the Fermi level in the non-interacting and in the Hartree approximations, shown in Figs. S2(c)-(d) respectively, feature a linear dependence on energy close to CNP due to the Dirac points and van Hove singularity peaks. Due to the bending, the van Hove singularities remain in an extended doping region in the Hartree approximation [53]. As a consequence of the larger value of the velocity matrix elements close to the Γ point than in the flat regions of the band structure the doping dependence of the dc conductivity in Figs. S2(e)-(f) is remarkably different to the dependence of the DOS at Fermi level, specially in the non-interacting limit.

The low frequency optical conductivity in the non-interacting and Hartree approximation is plotted in Figs. S2(g) and(h). For most of the frequencies shown, the optical intensity is dominated by interband transitions between the valence and the conduction flat bands. The contribution of the Drude weight to the optical conductivity is restricted to very low frequencies, consistent with the small scattering rate used in their calculation, $\hbar\Gamma_c = 0.05$ meV. The intensity due to interband transitions within the flat bands is much lower than the one from the transitions between the flat and the remote

bands [35, 37], Figs. 2(b) and (c). In both the non-interacting and the Hartree approximations, at the CNP the energy involved in the transitions between the valence and conduction flat bands is maximum at Γ point (~ 8 meV). In the absence of interactions, increasing the doping restricts the allowed transitions between the flat bands and consequently the optical intensity. This happens with little doping at very small frequencies for transitions around the K and K' points. Close to the Dirac points the states in the conduction (valence) band are filled (emptied) with small electron (hole) doping. At the Hartree level, once the upper conduction (valence) flat band crosses the Fermi level due to their bending at Γ , the interband transitions close to Γ become forbidden. Above $|\nu| > 1$ only the transitions with energy below $\hbar\omega \sim 2 - 3$ meV contribute.

The transitions between the flat and remote bands responsible for the intense peaks in the Hartree optical conductivity are sketched in Fig. S3 for the different ranges of doping: around CNP and hole and electron doped. The Hartree bending determines if the transitions around the Γ point, which give the largest contribution to the optical spectrum, are allowed or forbidden. For hole-doping, the most intense peaks are due to transitions between the upper and lower valence (UV and LV) remote bands and the flat bands (upper and lower UF and LF), while for electron doping the transitions between the UF and LF flat bands and the conduction remote bands (lower LC and upper UC) are the most important ones.

The Hartree deformation also modifies the frequency at which the interband transitions happen. In particular, the onset of the flat-remote transitions, UV-LF for hole doping and UF-LC for electron doping, decreases with increasing doping, as the UV (LC) approaches the chemical potential. The maximum intensity of the transitions between the flat bands and the upper conduction UC or lower valence LV remote bands happens at considerably higher energies than the ones involving the UV and LC, around 50 meV for the TBG parameters used. The onset of the interband transitions between the valence and the conduction remote bands (V-C) is around 75 meV, its dependence on doping is weak and their contribution to the optical intensity is much smaller, see also [37].

Interacting band structure

Figs. S4 and S5 show the evolution of the DMFT+H bandstructure for many different dopings in the range $-4 < \nu < 4$, which allows us to see the alternance of highly incoherent bands above the integers, evolving towards more coherent quasiparticle bands at the Fermi level below the integers. The incoherent spectral weight is spread over a wide range of energies. The formation of prominent Hubbard bands above the integers indicates the formation of local moments. With doping their width and intensity evolve, as spectral weight is transferred to form the quasiparticle. The Hubbard bands are bended towards Γ due to the hybridization between the local and the itinerant electrons. At nonzero integer fillings the DOS at the Fermi level is suppressed, but the still highly coherent, flat band remains very close to the Fermi level. Above the integer this band shifts away from the Fermi level becoming very incoherent and giving rise to a new Hubbard band.

Drude fittings

To fit the low-frequency conductivity to a Drude model

$$Re(\sigma(\Omega)) = \frac{D}{\pi(\Omega^2 + \Gamma_D^2)} \quad (S5)$$

we consider the ratio

$$\sigma_{\Omega^2}^{-1} = \frac{Re(\sigma(0))}{Re(\sigma(\Omega))} = \frac{\Omega^2}{\Gamma_D^2} + 1 \quad (S6)$$

Here D is the Drude weight and Γ_D the scattering rate obtained from the transport properties. For simplicity we refer to Γ_D as the Drude scattering rate. Fitting $\sigma_{\Omega^2}^{-1}$ to the above expression involves a single fitting parameter Γ_D and the validity of the approximation is clearly seen as a linear dependence of $\sigma_{\Omega^2}^{-1}$ on Ω^2 . We fit $\sigma_{\Omega^2}^{-1}$ to this expression up to $\hbar\Omega = 0.5$ meV. Beyond this value $\sigma_{\Omega^2}^{-1}$ starts to deviate from linearity for some dopings. The range of Ω in which the approximation works varies considerably between different fillings. We obtain the Drude weight from the dc conductivity $D = \pi\sigma_{DC}\Gamma_D$.

We have excluded from the fittings in Fig. 2 the dopings very close to the CNP ($-0.14 < \nu < 0.14$) and the integer dopings. From visual inspection, a Drude fitting is not valid for these dopings. In the case of the integers this is due to the vanishing conductivity at zero frequency. Close to the CNP the shape is not Drude-like due to the contribution of very low frequency interband transitions and the strong incoherence.

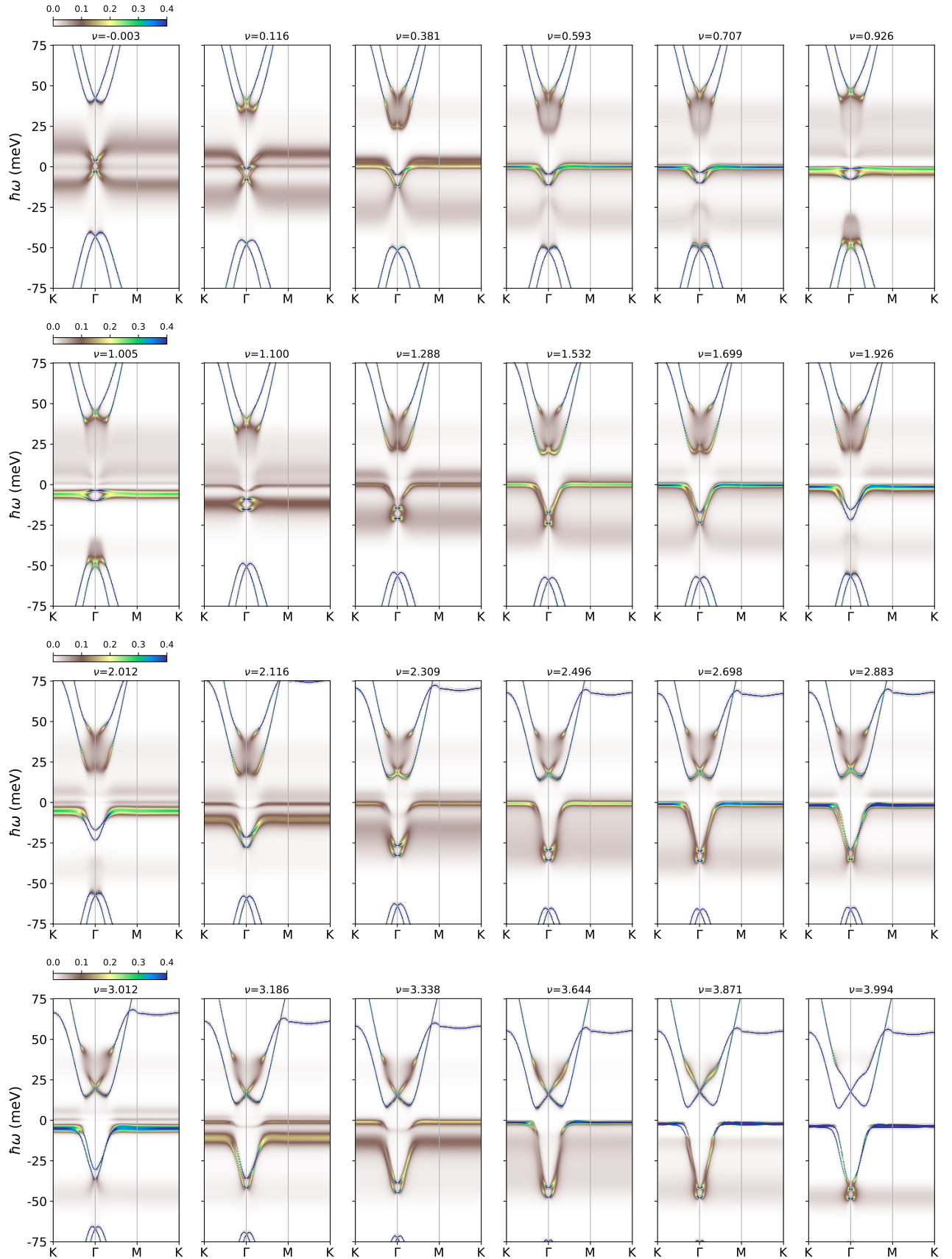


FIG. S4. Interacting band structure obtained in the DMFT+H calculations for different values of doping between $\nu = 0$ and $\nu = 4$, showing the doping and momentum dependent incoherence, the Hubbard bands and the bending of the band at the Fermi level.

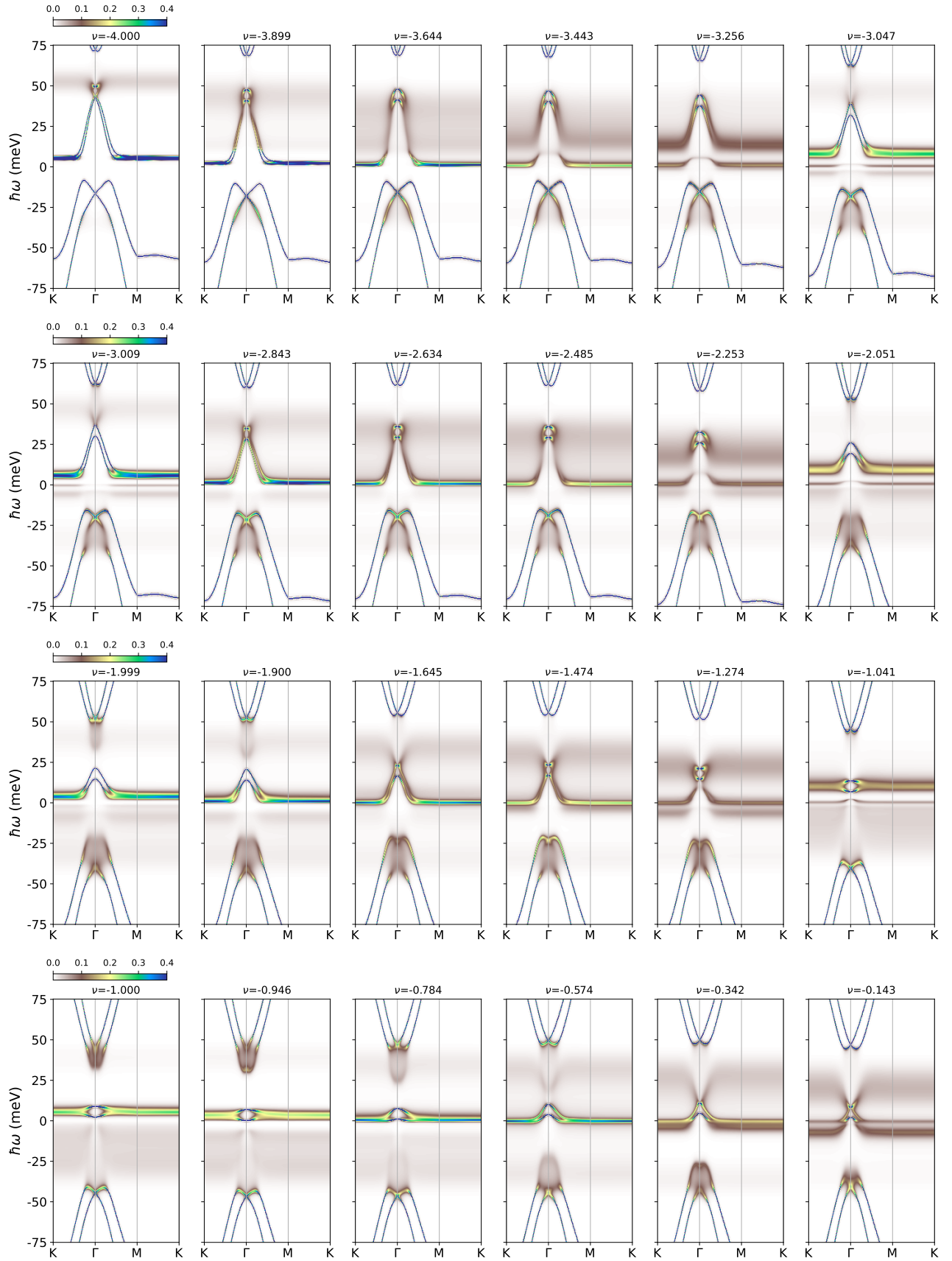


FIG. S5. Same as Fig. S4 but for hole doping.